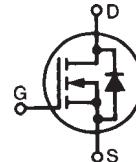


PolarHT™ Power MOSFET

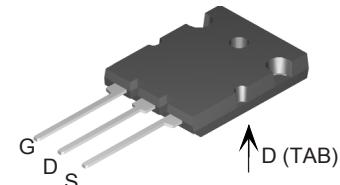
IXTK 150N15P IXTQ 150N15P

$V_{DSS} = 150$ V
 $I_{D25} = 150$ A
 $R_{DS(on)} \leq 13$ mΩ

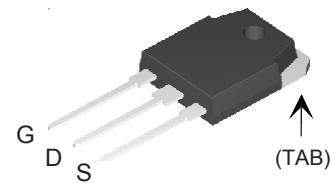
N-Channel Enhancement Mode
Avalanche Rated



TO-264 (IXTK)



TO-3P (IXTQ)



G = Gate
S = Source
TAB = Drain

Symbol	Test Conditions	Maximum Ratings		
V_{DSS}	$T_J = 25^\circ C$ to $175^\circ C$	150		V
V_{DGR}	$T_J = 25^\circ C$ to $175^\circ C$; $R_{GS} = 1 M\Omega$	150		V
V_{GS}	Continuous	± 20		V
V_{GSM}	Transient	± 30		V
I_{D25}	$T_c = 25^\circ C$	150		A
$I_{D(RMS)}$	External lead current limit	75		A
I_{DM}	$T_c = 25^\circ C$, pulse width limited by T_{JM}	340		A
I_{AR}	$T_c = 25^\circ C$	60		A
E_{AR}	$T_c = 25^\circ C$	80		mJ
E_{AS}	$T_c = 25^\circ C$	2.5		J
dv/dt	$I_s \leq I_{DM}$, $di/dt \leq 100$ A/ μ s, $V_{DD} \leq V_{DSS}$, $T_J \leq 175^\circ C$, $R_G = 4 \Omega$	10		V/ns
P_D	$T_c = 25^\circ C$	714		W
T_J		-55 ... +175		°C
T_{JM}		175		°C
T_{stg}		-55 ... +175		°C
T_L	1.6 mm (0.062 in.) from case for 10 s	300		°C
T_{SOOLD}	Plastic body for 10 s	260		°C
M_d	Mounting torque	$1.13/10$ Nm/lb.in.		
Weight	TO-3P TO-264	5.5 10		g g
Symbol	Test Conditions	Characteristic Values		
$(T_J = 25^\circ C$, unless otherwise specified)		Min.	Typ.	Max.
BV_{DSS}	$V_{GS} = 0 V$, $I_D = 250 \mu A$	150		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	3.0		5.0 V
I_{GSS}	$V_{GS} = \pm 20 V_{DC}$, $V_{DS} = 0$		± 100	nA
I_{DSS}	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$	$T_J = 175^\circ C$	25	μA
			500	μA
$R_{DS(on)}$	$V_{GS} = 10 V$, $I_D = 0.5 I_{D25}$ Pulse test, $t \leq 300 \mu s$, duty cycle d $\leq 2\%$		13	mΩ

Features

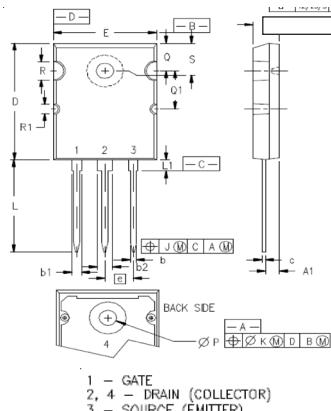
- International standard packages
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
 - easy to drive and to protect

Advantages

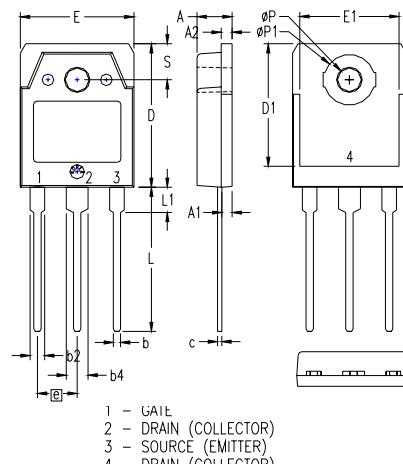
- Easy to mount
- Space savings
- High power density

Symbol	Test Conditions	Characteristic Values			
		($T_J = 25^\circ C$, unless otherwise specified)	Min.	Typ.	Max.
g_{fs}	$V_{DS} = 10 V$; $I_D = 0.5 I_{D25}$, pulse test	55	80	S	
C_{iss} C_{oss} C_{rss}	$V_{GS} = 0 V$, $V_{DS} = 25 V$, $f = 1 MHz$	5800	pF		
		1730	pF		
		400	pF		
$t_{d(on)}$ t_r $t_{d(off)}$ t_f	$V_{GS} = 10 V$, $V_{DS} = 0.5 V_{DSS}$, $I_D = I_{D25}$ $R_G = 3.3 \Omega$ (External)	30	ns		
		33	ns		
		100	ns		
		28	ns		
$Q_{g(on)}$ Q_{gs} Q_{gd}	$V_{GS} = 10 V$, $V_{DS} = 0.5 V_{DSS}$, $I_D = 0.5 I_{D25}$	190	nC		
		40	nC		
		105	nC		
R_{thJC}			0.21	$^\circ C/W$	
R_{thCK}	TO-3P	0.21	$^\circ C/W$		
R_{thCS}	TO-264	0.15	$^\circ C/W$		

Symbol	Test Conditions	Characteristic Values			
		($T_J = 25^\circ C$, unless otherwise specified)	Min.	Typ.	Max.
I_s	$V_{GS} = 0 V$		150	A	
I_{SM}	Repetitive		340	A	
V_{SD}	$I_F = I_s$, $V_{GS} = 0 V$, Pulse test, $t \leq 300 \mu s$, duty cycle $d \leq 2\%$		1.5	V	
t_{rr}	$I_F = 25 A$ $-di/dt = 100 A/\mu s$ $V_R = 100 V$, $V_{GS} = 0 V$	150	ns		
		2.3	μC		

TO-264 (IXTK) Outline


SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.185	.209	4.70	5.31
A1	.102	.118	2.59	3.00
b	.037	.055	0.94	1.40
b1	.087	.102	2.21	2.59
b2	.110	.126	2.79	3.20
c	.017	.029	0.43	0.74
D	1.007	1.047	25.58	26.59
E	.760	.799	19.30	20.29
e	.215BSC		5.46 BSC	
J	.000	.010	0.00	0.25
K	.000	.010	0.00	0.25
L	.779	.842	19.79	21.39
L1	.087	.102	2.21	2.59
ØP	.122	.138	3.10	3.51
Q	.240	.256	6.10	6.50
Q1	.330	.346	8.38	8.79
ØR	.155	.187	3.94	4.75
ØR1	.085	.093	2.16	2.36
S	.243	.253	6.17	6.43

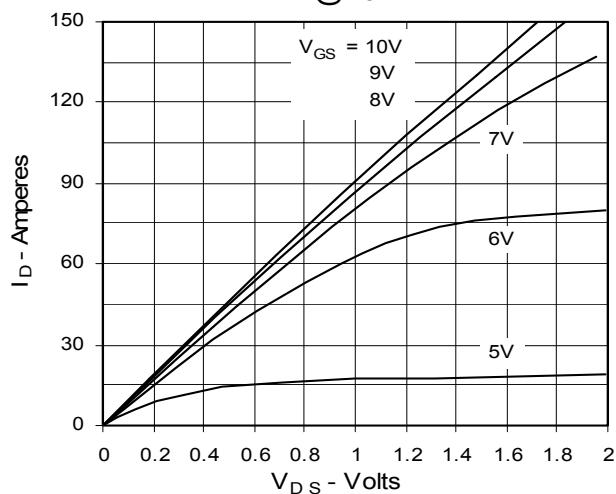
TO-3P (IXTQ) Outline


SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.185	.193	4.70	4.90
A1	.051	.059	1.30	1.50
A2	.057	.065	1.45	1.65
b	.035	.045	0.90	1.15
b2	.075	.087	1.90	2.20
b4	.114	.126	2.90	3.20
c	.022	.031	0.55	0.80
D	.780	.799	19.80	20.30
D1	.665	.677	16.90	17.20
E	.610	.622	15.50	15.80
E1	.531	.539	13.50	13.70
e	.215 BSC		5.45 BSC	
L	.779	.795	19.80	20.20
L1	.134	.142	3.40	3.60
ØP	.126	.134	3.20	3.40
ØP1	.272	.280	6.90	7.10
S	.193	.201	4.90	5.10

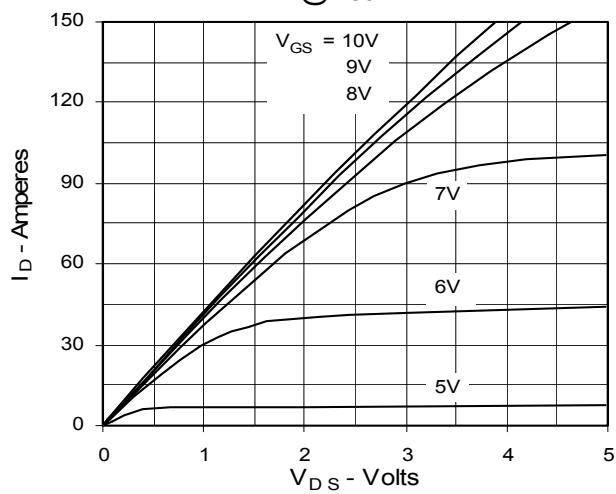
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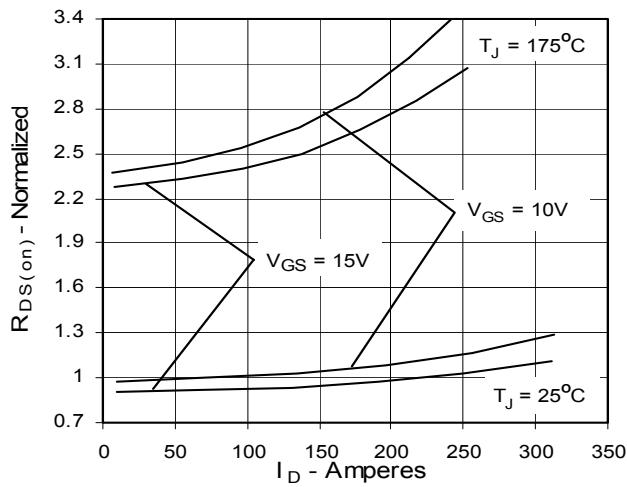
**Fig. 1. Output Characteristics
@ 25°C**



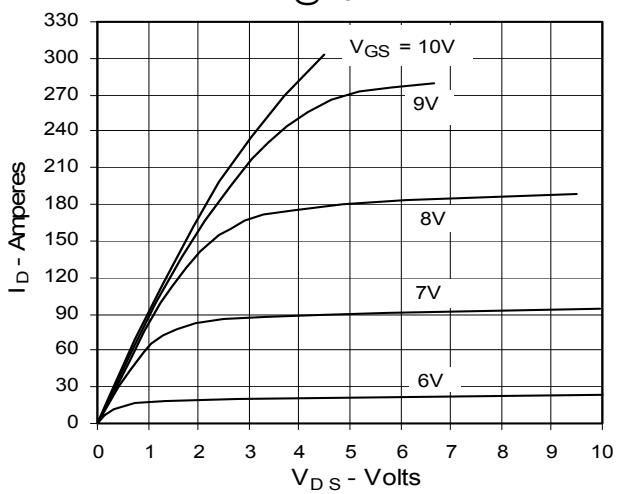
**Fig. 3. Output Characteristics
@ 150°C**



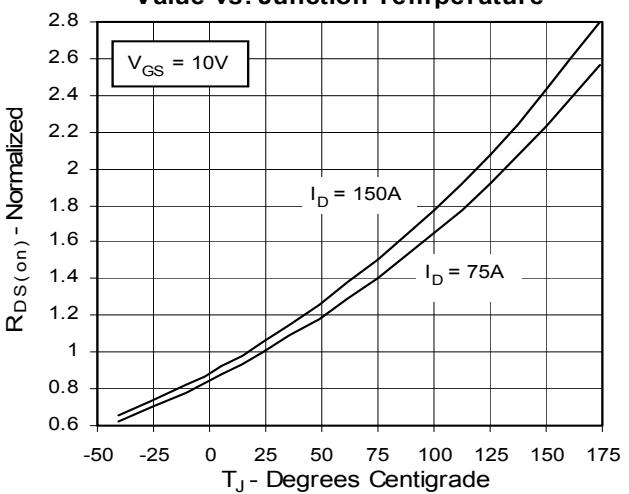
**Fig. 5. $R_{DS(on)}$ Normalized to 0.5 I_{D25}
Value vs. Drain Current**



**Fig. 2. Extended Output Characteristics
@ 25°C**



**Fig. 4. $R_{DS(on)}$ Normalized to 0.5 I_{D25}
Value vs. Junction Temperature**



**Fig. 6. Drain Current vs. Case
Temperature**

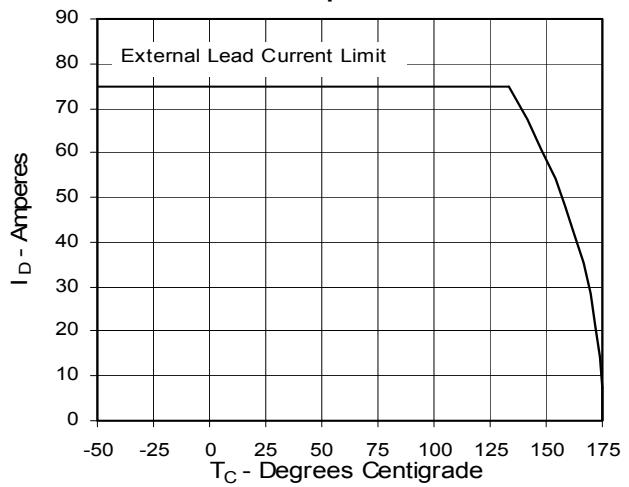


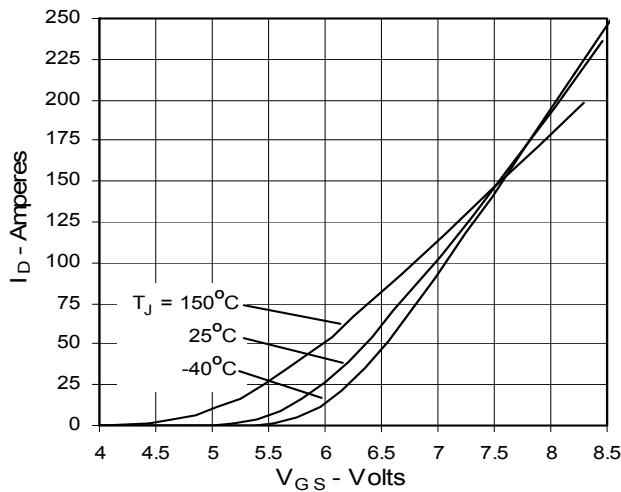
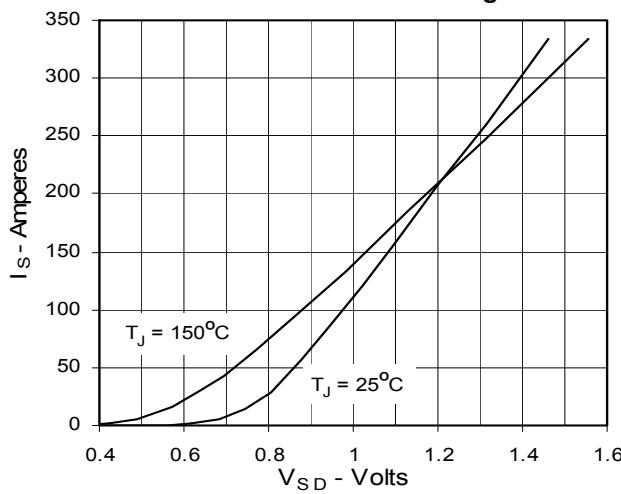
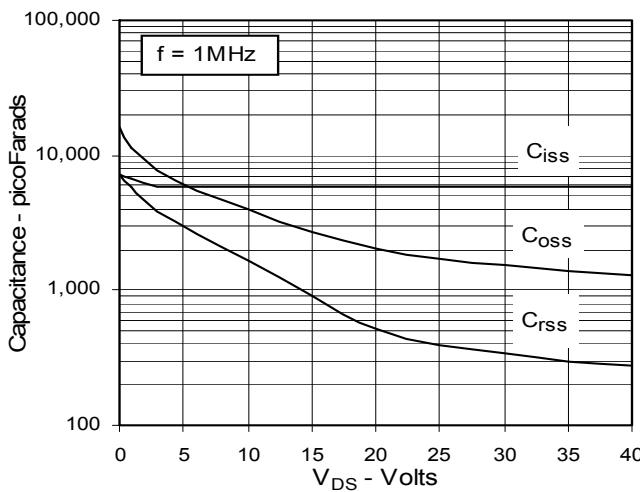
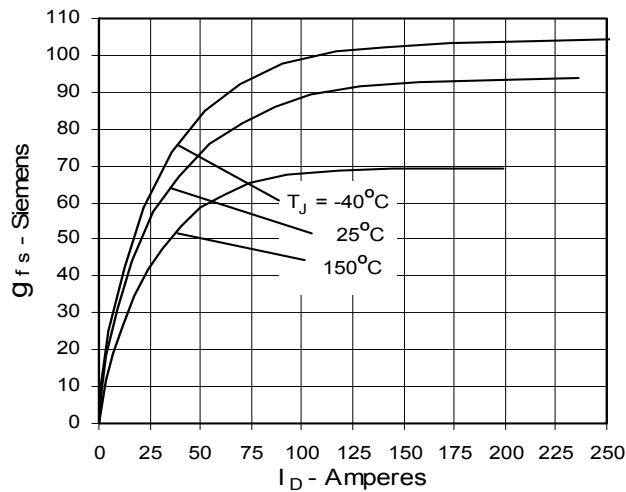
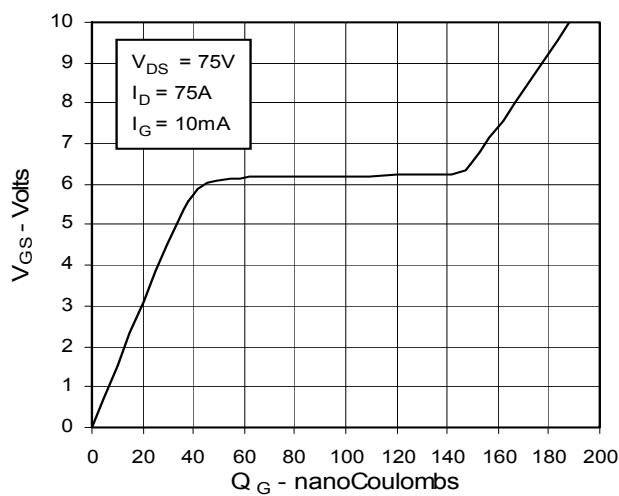
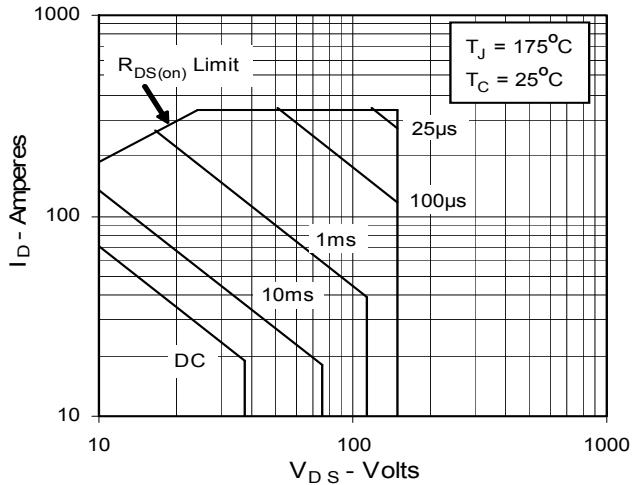
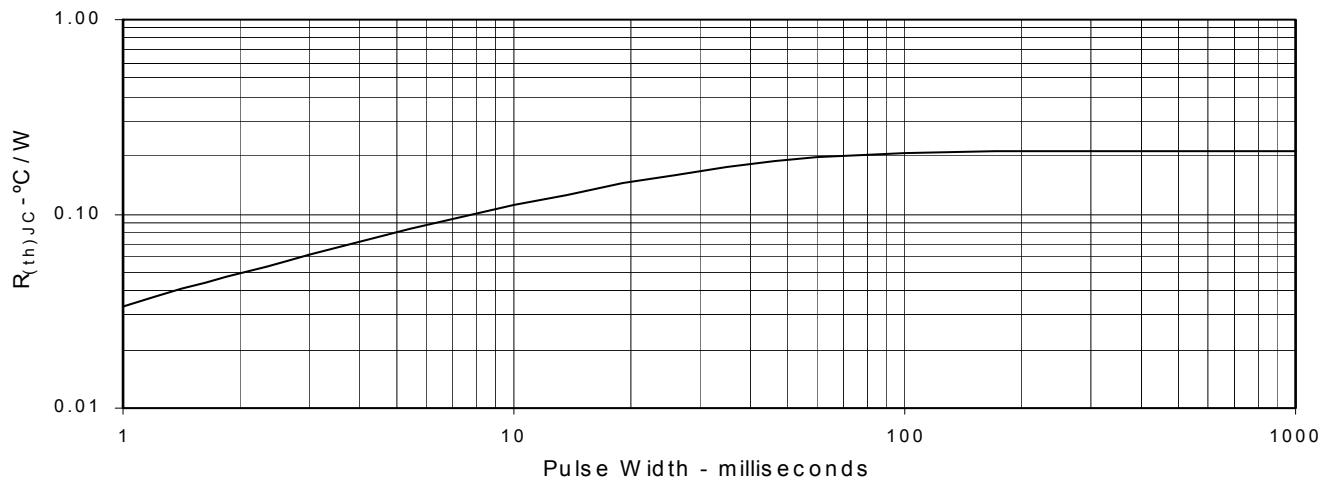
Fig. 7. Input Admittance

Fig. 9. Source Current vs. Source-To-Drain Voltage

Fig. 11. Capacitance

Fig. 8. Transconductance

Fig. 10. Gate Charge

Fig. 12. Forward-Bias Safe Operating Area


Fig. 13. Maximum Transient Thermal Resistance



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